P-Channel 60-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

Typical Applications:

- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

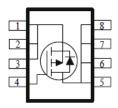
PRODUCT SUMMARY				
V _{DS} (V)	I□ (A)			
-60	12 @ V _{GS} = -10V	-17		
	16 @ V _{GS} = -4.5V	-15		







DFN5X6-8L



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED)							
Parameter				Limit	Units		
Drain-Source Voltage				-60	V		
Gate-Source Voltage	age				V		
Continuous Drain Current ^a		Γ _A =25°C		-17			
Continuous Drain Current		Γ _A =70°C	l _D	-13.4	Α		
Pulsed Drain Current ^b		I_{DM}	-50				
Continuous Source Current (Diode Conduction) ^a	I _S	-7.1	Α				
Davier Dissipation a		Γ _A =25°C	P _D	5	W		
Power Dissipation ^a			гD	3.2	VV		
Operating Junction and Storage Temperature Range				-55 to 150	°C		

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Maximum	Units				
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	25	°C/W			
Maximum Junction-to-Ambient	Steady State		65	C/VV			

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Electrical Characteristics

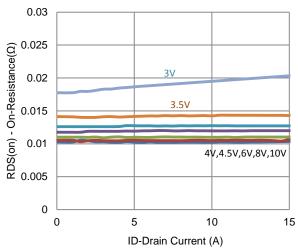
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-1			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zara Cata Valtaga Drain Current	_	$V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}$			-1 uA		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-25	uA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-20			Α	
Drain Cauras On Basistanas a	r	$V_{GS} = -10 \text{ V}, I_D = -13.2 \text{ A}$			12	mΩ	
Drain-Source On-Resistance ^a	r _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -10.6 \text{ A}$			16	11122	
Forward Transconductance a	g _{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -13.2 \text{ A}$		30		S	
Diode Forward Voltage ^a	V_{SD}	$I_S = -3.6 \text{ A}, V_{GS} = 0 \text{ V}$		-0.75		V	
		Dynamic ^b					
Total Gate Charge	Q_g	$V_{DS} = -30 \text{ V}, V_{GS} = -4.5 \text{ V},$		90		nC	
Gate-Source Charge	Q_{gs}	$I_{DS} = -30 \text{ V}, V_{GS} = -4.3 \text{ V},$ $I_{D} = -13.2 \text{ A}$		22			
Gate-Drain Charge	Q_gd	10 = 10.2 A		37			
Turn-On Delay Time	t _{d(on)}	$V_{DS} = -30 \text{ V}, R_{L} = 2.3 \Omega,$		14			
Rise Time	t _r	$V_{DS} = -30 \text{ V}, K_L - 2.3 \Omega,$ $I_D = -13.2 \text{ A},$		29		ne	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = -10 \text{ V}, R_{GEN} = 6 \Omega$		303		ns	
Fall Time	t _f	VGEN = 10 V, NGEN = 0 12		109			
Input Capacitance	C _{iss}			9258			
Output Capacitance	C _{oss}	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ Mhz}$		618		pF	
Reverse Transfer Capacitance	C_{rss}			500			

Notes

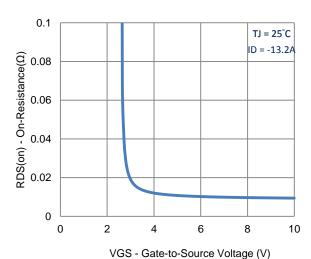
- Pulse test: PW <= 300us duty cycle <= 2%.
- Guaranteed by design, not subject to production testing. b.

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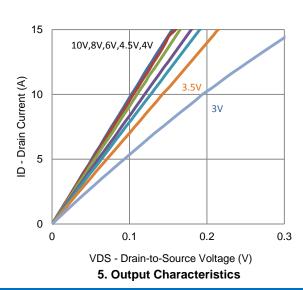
Typical Electrical Characteristics

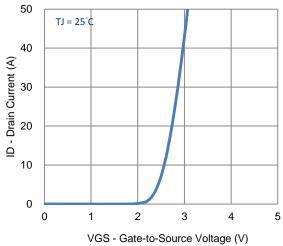


1. On-Resistance vs. Drain Current

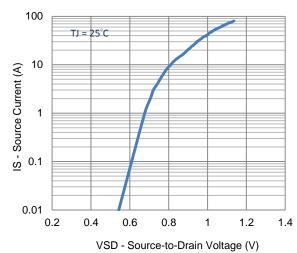


3. On-Resistance vs. Gate-to-Source Voltage

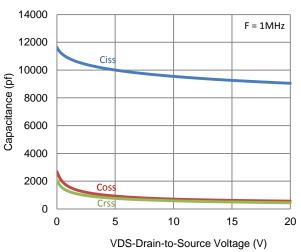




2. Transfer Characteristics

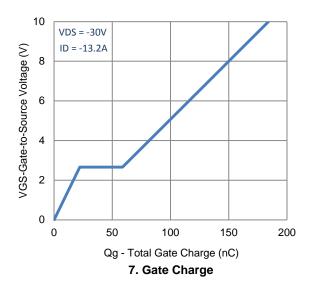


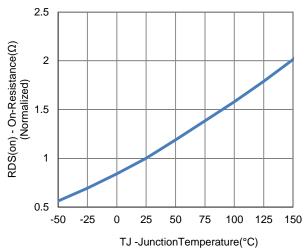
4. Drain-to-Source Forward Voltage



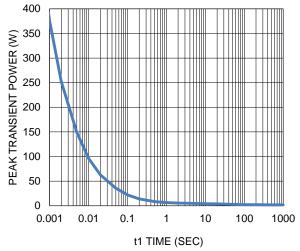
6. Capacitance

Typical Electrical Characteristics





8. Normalized On-Resistance Vs Junction Temperature



VDS Drain to Source Voltage (V)

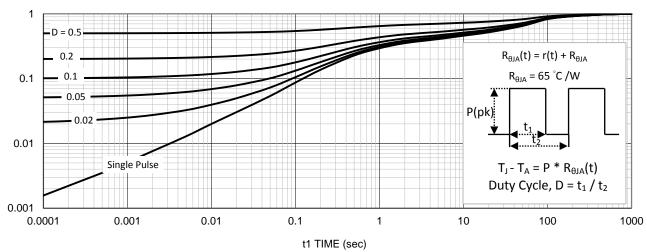
9. Safe Operating Area

100

1000

10



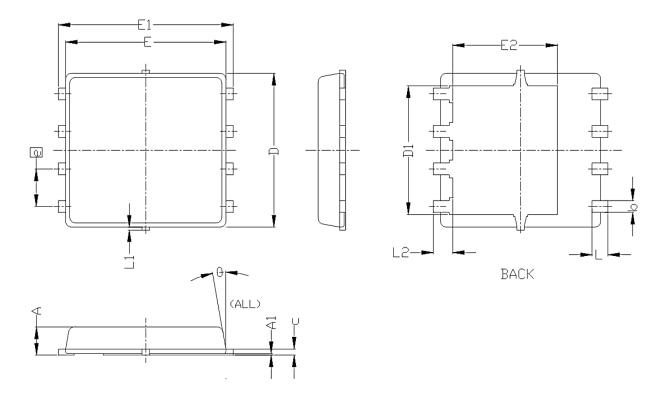


11. Normalized Thermal Transient Junction to Ambient

0.01

0.1

Package Information



SYMBOLS	DIMENS	IONS IN MILLI	METERS	DIMENSIONS IN INCHES		
STMBULS	MIN	NOM	MAX	MIN	NOM	MAX
A	0.85	0. 95	1.00	0.033	0.037	0.039
Al	0.00		0.05	0.000		0.002
b	0.30	0.40	0.50	0.012	0.016	0.020
с	0. 15	0. 20	0. 25	0.006	0.008	0.010
D	5. 20 BSC			0. 205 BSC		
D1	4. 35 BSC			0. 171 BSC		
E	5, 55 BSC			0. 219 BSC		
El	6. 05 BSC			0. 238 BSC		
E2	3. 62 BSC			0. 143 BSC		
e	1. 27 BSC			0. 050 BSC		
L	0.45	0.55	0.65	0.018	0.022	0.026
L1	0		0.15	0		0.006
L2	0.68 REF			0. 027 REF		
θ	0°		10°	0°		10°